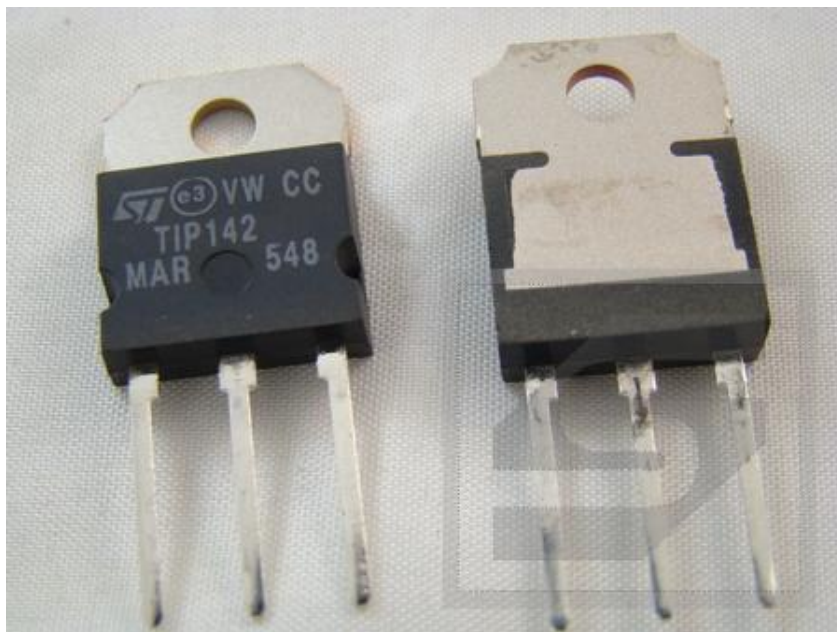




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TIP142;ST;TO247;tranzystor; NPN;Darlington+dioda;10A;100V;125W



Dane techniczne:

Nazwa: TIP142

Typ tranzystora: bipolarny

Układ Darlingtona + dioda

Kierunek przewodnictwa: NPN

Prąd kolektora: 10A

Napięcie kolektor-emiter: 100V

Moc: 125W

Montaż: przewlekany(THT)

Obudowa: TO247

Producent: ST

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TIP140/141/142 TIP145/146/147

COMPLEMENTARY SILICON POWER DARLINGTON TRANSISTORS

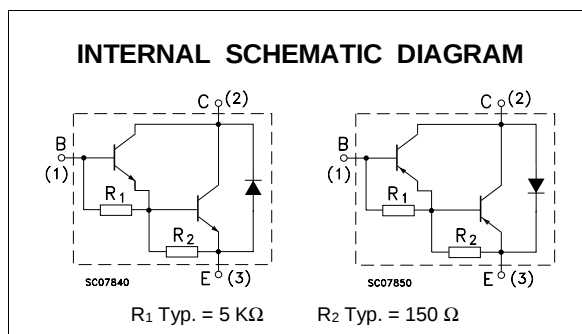
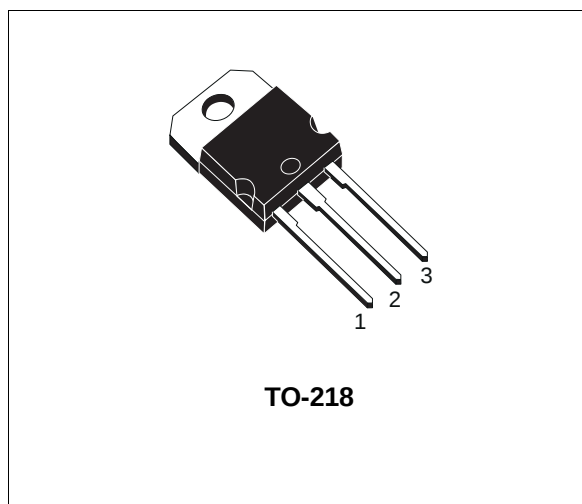
- TIP141, TIP142, TIP145 AND TIP147 ARE STMicroelectronics PREFERRED SALESTYPES
- COMPLEMENTARY PNP - NPN DEVICES
- MONOLITHIC DARLINGTON CONFIGURATION
- INTEGRATED ANTIPARALLEL COLLECTOR-EMITTER DIODE

APPLICATIONS

- LINEAR AND SWITCHING INDUSTRIAL EQUIPMENT

DESCRIPTION

The TIP140, TIP141 and TIP142 are silicon Epitaxial-Base NPN power transistors in monolithic Darlington configuration, mounted in TO-218 plastic package. They are intended for use in power linear and switching applications. The complementary PNP types are TIP145, TIP146 and TIP147 respectively.



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value				Unit
		NPN	TIP140	TIP141	TIP142	
V _{CBO}	Collector-Base Voltage (I _E = 0)	PNP	TIP145	TIP146	TIP147	
V _{CBO}	Collector-Base Voltage (I _E = 0)		60	80	100	V
V _{CEO}	Collector-Emitter Voltage (I _B = 0)		60	80	100	V
V _{EBO}	Emitter-Base Voltage (I _C = 0)		5			V
I _C	Collector Current		10			A
I _{CM}	Collector Peak Current		20			A
I _B	Base Current		0.5			A
P _{tot}	Total Dissipation at T _{case} ≤ 25 °C		125			W
T _{stg}	Storage Temperature		-65 to 150			°C
T _j	Max. Operating Junction Temperature		150			°C

For PNP types voltage and current values are negative.

TIP140 / TIP141 / TIP142 / TIP145 / TIP146 / TIP147

THERMAL DATA

R _{thj-case}	Thermal Resistance Junction-case	Max	1	°C/W
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ELECTRICAL CHARACTERISTICS (T_{case} = 25 °C unless otherwise specified)

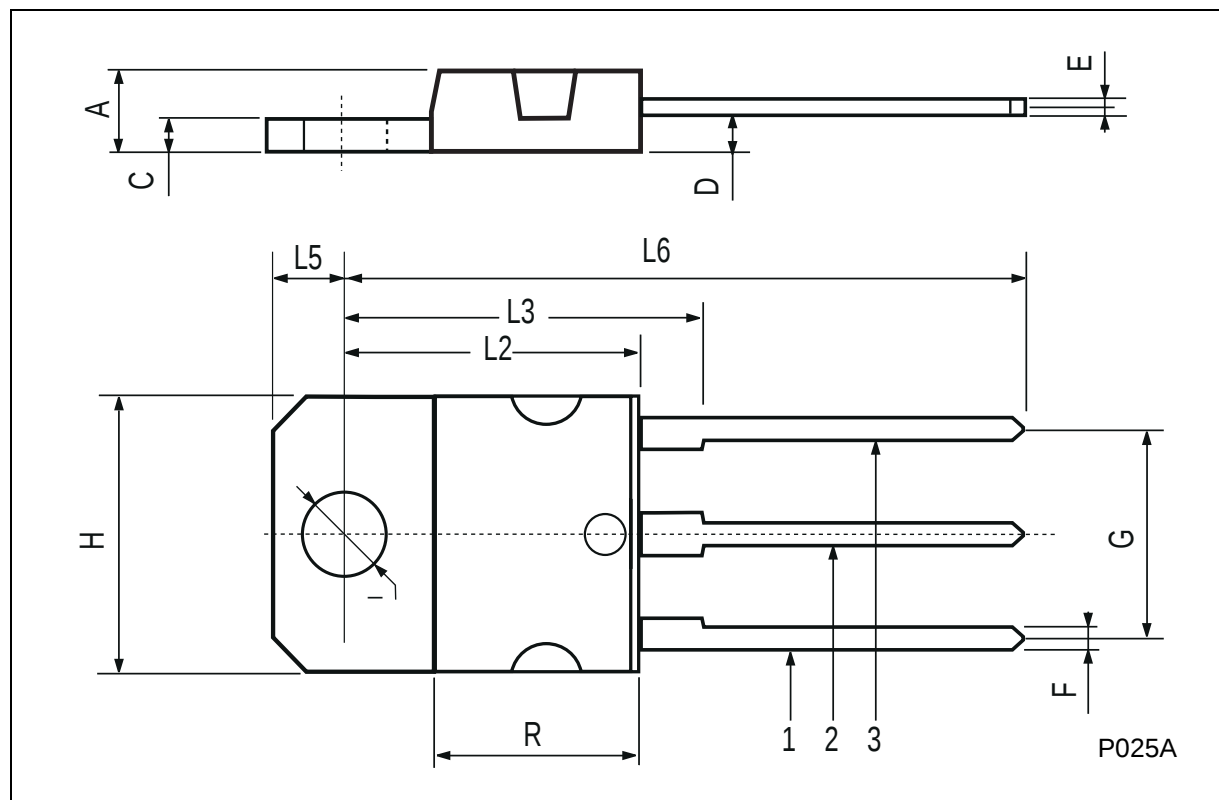
Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
I _{CBO}	Collector Cut-off Current (I _E = 0)	for TIP140/145 V _{CB} = 60 V for TIP141/146 V _{CB} = 80 V for TIP142/147 V _{CB} = 100 V			1 1 1	mA mA mA
I _{CEO}	Collector Cut-off Current (I _B = 0)	for TIP140/145 V _{CE} = 30 V for TIP141/146 V _{CE} = 40 V for TIP142/147 V _{CE} = 50 V			2 2 2	mA mA mA
I _{EBO}	Emitter Cut-off Current (I _C = 0)	V _{EB} = 5 V			2	mA
V _{CEO(sus)} *	Collector-Emitter Sustaining Voltage (I _B = 0)	I _C = 30 mA for TIP140/145 for TIP141/146 for TIP142/147	60 80 100			V V V
V _{CE(sat)} *	Collector-Emitter Saturation Voltage	I _C = 5 A I _B = 10 mA I _C = 10 A I _B = 40 mA			2 3	V V
V _{BE(on)} *	Base-Emitter Voltage	I _C = 10 A V _{CE} = 4 V			3	V
h _{FE} *	DC Current Gain	I _C = 5 A V _{CE} = 4 V I _C = 10 A V _{CE} = 4 V	1000 500			
t _{on} t _{off}	RESISTIVE LOAD Turn-on Time Turn-off Time	I _C = 10 A I _{B1} = 40 mA I _{B2} = -40 mA R _L = 3 Ω		0.9 4		μs μs

For PNP types voltage and current values are negative.

* Pulsed: Pulse duration = 300 μs, duty cycle 1.5 %

TO-218 (SOT-93) MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	4.7		4.9	0.185		0.193
C	1.17		1.37	0.046		0.054
D		2.5			0.098	
E	0.5		0.78	0.019		0.030
F	1.1		1.3	0.043		0.051
G	10.8		11.1	0.425		0.437
H	14.7		15.2	0.578		0.598
L2	–		16.2	–		0.637
L3		18			0.708	
L5	3.95		4.15	0.155		0.163
L6		31			1.220	
R	–		12.2	–		0.480
Ø	4		4.1	0.157		0.161



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